## onsemi

MARKING

### TinyLogic HS 2-Input NOR Gate

## NC7S02

#### Description

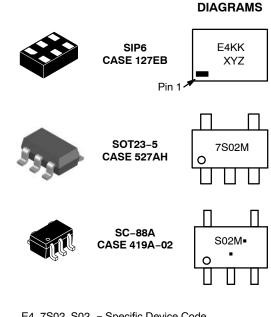
The NC7S02 is a single 2–Input high performance CMOS NOR Gate. Advanced Silicon Gate CMOS fabrication assures high speed and low power circuit operation over a broad  $V_{CC}$  range. ESD protection diodes inherently guard both inputs and output with respect to the  $V_{CC}$  and GND rails. Three stages of gain between inputs and outputs assures high noise immunity and reduced sensitivity to input edge rate.

#### Features

- Space Saving SOT23-5 and SC88A 5-Lead Packages
- Ultra Small MicroPak<sup>™</sup> Leadless Package
- High Speed:  $t_{PD} = 3.5$  ns Typ
- Low Quiescent Power:  $I_{CC} < 1 \mu A$
- Balanced Output Drive: 2 mA I<sub>OL</sub>, -2 mA I<sub>OH</sub>
- Broad V<sub>CC</sub> Operating Range: 2 V 6 V
- Balanced Propagation Delays
- Specified for 3 V Operation
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



Figure 1. Logic Symbol



E4, 7S02, S02	= Specific Device Code
KK	= 2-Digit Lot Run Traceability Code
XY	= 2-Digit Date Code Format
Z	= Assembly Plant Code
M	= Date Code*

\*Date Code orientation and/or position may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

#### **Pin Configurations**

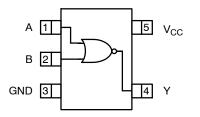
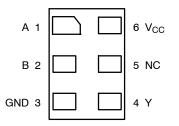


Figure 2. SC-88A and SOT23-5 (Top View)

#### **PIN DESCRIPTIONS**

Pin Name	Description
A, B	Inputs
Y	Output
NC	No Connect



#### Figure 3. MicroPak (Top Through View)

#### **FUNCTION TABLE** $(Y = \overline{A + B})$

Inp	Output	
А	В	Y
L	L	Н
L	Н	L
Н	L	L
Н	Н	L

H = HIGH Logic Level L = LOW Logic Level

#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	ol Parameter		Min	Max	Unit
V <sub>CC</sub>	Supply Voltage		-0.5	6.5	V
I <sub>IK</sub>	DC Input Diode Current	V <sub>IN</sub> < 0 V	-	-20	mA
		V <sub>IN</sub> > V <sub>CC</sub>	-	+20	
V <sub>IN</sub>	DC Input Voltage	•	-0.5	V <sub>CC</sub> + 0.5	V
I <sub>OK</sub>	DC Output Diode Current	V <sub>OUT</sub> < 0 V	-	-20	mA
		V <sub>OUT</sub> > V <sub>CC</sub>	-	+20	1
V <sub>OUT</sub>	DC Output Voltage		-0.5	V <sub>CC</sub> + 0.5	V
I <sub>OUT</sub>	DC Output Source or Sink Curren	nt	-	±12.5	mA
$I_{CC} \text{ or } I_{GND}$	DC V <sub>CC</sub> or Ground Current per C	Putput Pin	-	±25	mA
T <sub>STG</sub>	Storage Temperature     Junction Temperature     Lead Temperature (Soldering, 10 Seconds)		-65	+150	°C
TJ			-	+150	°C
ΤL			-	+260	°C
PD	Power Dissipation in Still Air	SOT23-5	-	390	mW
		SC-88A	-	332	
		MicroPak-6	-	812	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Conditions	Min	Мах	Unit
V <sub>CC</sub>	Supply Voltage		2.0	6.0	V
V <sub>IN</sub>	Input Voltage		0	V <sub>CC</sub>	V
V <sub>OUT</sub>	Output Voltage		0	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature		-40	+85	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Times	V <sub>CC</sub> at 2.0 V	0	20	ns/V
		V <sub>CC</sub> at 3.0 V	0	20	
		V <sub>CC</sub> at 4.5 V	0	10	
		V <sub>CC</sub> at 6.0 V	0	5	
$\theta_{JA}$	Thermal Resistance	SOT23-5	-	320	°C/W
		SC-88A	-	377	
		MicroPak-6	-	154	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability. 1. Unused inputs must be held HIGH or LOW. They may not float.

#### **DC ELECTICAL CHARACTERISTICS**

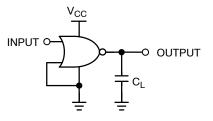
				٦	Γ <sub>A</sub> = +25°C	;	T <sub>A</sub> = -40	to +85°C	
Symbol	Parameter	V <sub>CC</sub> (V)	Conditions	Min	Тур	Max	Min	Max	Unit
V <sub>IH</sub>	HIGH Level Input Voltage	2.0 3.0 – 6.0		1.50 0.7 V <sub>CC</sub>	-		1.50 0.7 V <sub>CC</sub>	-	V
V <sub>IL</sub>	LOW Level Input Voltage	2.0 3.0 – 6.0				0.50 0.3 V <sub>CC</sub>		0.50 0.3 V <sub>CC</sub>	V
V <sub>OH</sub>	HIGH Level Output Voltage	2.0 3.0 4.5 6.0	$    I_{OH} = -20 \ \mu A \\ V_{IN} = V_{IH} \ or \ V_{IL} $	1.90 2.90 4.40 5.90	2.0 3.0 4.5 6.0	- - - -	1.90 2.90 4.40 5.90	- - - -	V
		3.0 4.5 6.0	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -1.3 \text{ mA}$ $I_{OH} = -2.0 \text{ mA}$ $I_{OH} = -2.6 \text{ mA}$	2.68 4.18 5.68	2.85 4.35 5.85		2.63 4.13 5.63	- - -	V
V <sub>OL</sub>	LOW Level Output Voltage	2.0 3.0 4.5 6.0		- - - -	0.0 0.0 0.0 0.0	0.10 0.10 0.10 0.10	- - - -	0.10 0.10 0.10 0.10	V
		3.0 4.5 6.0	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 1.3 \text{ mA}$ $I_{OL} = 2.0 \text{ mA}$ $I_{OL} = 2.6 \text{ mA}$	- - -	0.1 0.1 0.1	0.26 0.26 0.26	- - -	0.33 0.33 0.33	V
I <sub>IN</sub>	Input Leakage Current	6.0	V <sub>IN</sub> = V <sub>CC</sub> , GND	-	-	±0.1	-	±1.0	μA
I <sub>CC</sub>	Quiescent Supply Current	6.0	$V_{IN} = V_{CC}, \text{ GND}$	-	-	1.0	-	10.0	μA

#### AC ELECTRICAL CHARACTERISTICS

					Γ <sub>A</sub> = +25°C	;	T <sub>A</sub> = -40	to +85°C	
Symbol	Parameter	V <sub>CC</sub> (V)	Conditions	Min	Тур	Max	Min	Max	Unit
t <sub>PLH</sub> ,	Propagation Delay (Figure 4, 6)	5.0	C <sub>L</sub> = 15 pF	-	3.5	15	-	-	ns
t <sub>PHL</sub>		2.0 3.0 4.5 6.0	C <sub>L</sub> = 50 pF	- - -	19 10.5 7.5 6.5	100 27 20 17	- - -	125 35 25 21	ns
t <sub>TLH</sub> ,	Output Transition Time	5.0	C <sub>L</sub> = 15 pF	-	3	10	-	-	ns
t <sub>THL</sub>	(Figure 4, 6)	2.0 3.0 4.5 6.0	C <sub>L</sub> = 50 pF	- - -	25 16 11 9	125 35 25 21	- - -	155 45 31 26	ns
C <sub>IN</sub>	Input Capacitance	Open		-	2	10	-	10	pF
C <sub>PD</sub>	Power Dissipation Capacitance (Figure 5)	5.0	(Note 2)	-	6	_	_	-	pF

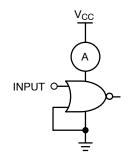
2.  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I<sub>CCD</sub>) at no output loading and operating at 50% duty cycle.  $C_{PD}$  is related to I<sub>CCD</sub> dynamic operating current by the expression: I<sub>CCD</sub> = ( $C_{PD}$ ) (V<sub>CC</sub>) ( $f_{IN}$ ) + (I<sub>CC</sub>static).

#### AC Loading and Waveforms



 $C_L$  includes load and stray capacitance Input PRR = 1.0 MHz;  $t_W$  = 500 ns

#### Figure 4. AC Test Circuit



Input = AC Waveform; PRR = Variable; Duty Cycle = 50%.

Figure 5. I<sub>CCD</sub> Test Circuit

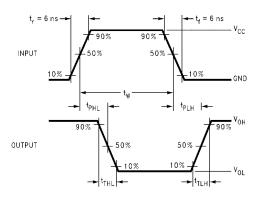


Figure 6. AC Waveforms

#### **ORDERING INFORMATION**

Order Number	Top Mark	Package Description	Shipping <sup>†</sup>
NC7S02M5X	7S02	SOT23-5	3000 / Tape & Reel
NC7S02M5X-L22090	7S02	SOT23-5	3000 / Tape & Reel
NC7S02P5X	S02	SC-88A	3000 / Tape & Reel
NC7S02P5X-L22057	S02	SC-88A	3000 / Tape & Reel
NC7S02L6X	E4	SIP6, MicroPak	5000 / Tape & Reel
NC7S02L6X-L22175	E4	SIP6, MicroPak	5000 / Tape & Reel

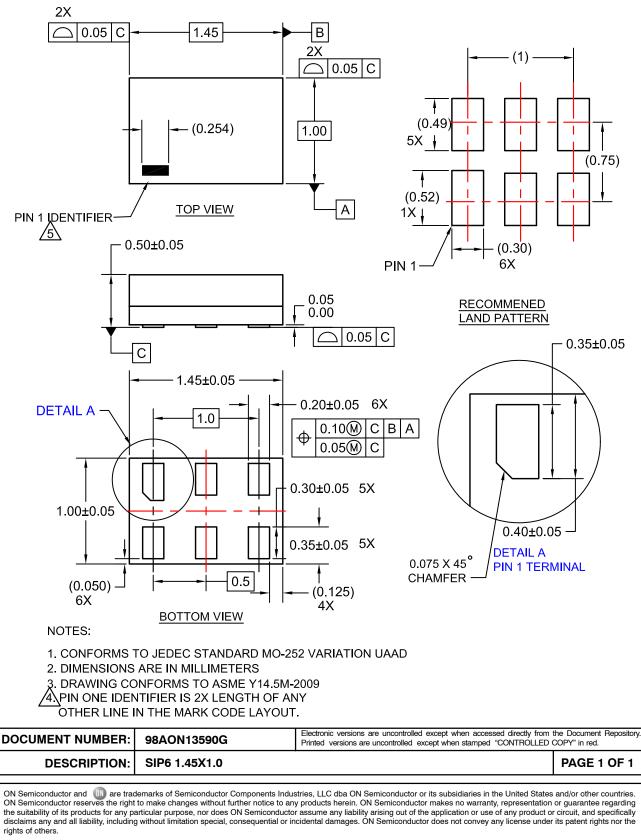
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MicroPak is trademark of Semiconductor Components Industries, LLC (SCILLC) or its subsidiaries in the United States and/or other countries.



SIP6 1.45X1.0 CASE 127EB ISSUE O

DATE 31 AUG 2016



0

# onsemi

DATE 11 APR 2023

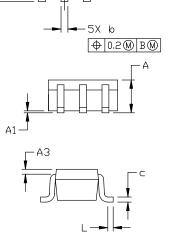


SCALE 2:1

#### **SC-88A (SC-70-5/SOT-353)** CASE 419A-02 ISSUE M

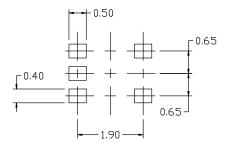
NDTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. 419A-01 DBSDLETE. NEW STANDARD 419A-02
- 4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.



e

F1



#### RECOMMENDED MOUNTING FOOTPRINT

For additional information on our
Pb-Free strategy and soldering details,
please download the DN Semiconductor
Soldering and Mounting Techniques
Reference Manual, SDLDERRM/D.

DIM	MILLIMETERS				
ויונע	MIN.	NDM.	MAX,		
А	0.80	0.95	1.10		
A1					
A3		0.20 REF			
b	0.10	0.20	0,30		
C	0.10		0,25		
D	1.80	2.00	5.20		
E	2.00	2.10	5.20		
E1	1.15	1.25	1.35		
e	0.65 BSC				
L	0.10	0.15	0.30		

#### **GENERIC MARKING**





\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

PIN 1. BASE   PIN 1. ANODE   PIN 1. ANODE 1   PIN 1. SOURCE 1   PIN 1. CATHODE     2. EMITTER   2. EMITTER   2. N/C   2. DRAIN 1/2   2. COMMON ANODE     3. BASE   3. BASE   3. ANODE 2   3. SOURCE 1   3. CATHODE 2     4. COLLECTOR   4. COLLECTOR   4. CATHODE 2   4. GATE 1   4. CATHODE 3     5. COLLECTOR   5. CATHODE   5. CATHODE 1   5. GATE 2   5. CATHODE 4     STYLE 6:   STYLE 7:   STYLE 8:   STYLE 9:   Note: Please refer to datasheet for style callout. If style type is not callout. COLLECTOR     3. EMITTER 1   3. BASE   3. N/C   3. ANODE 2   CATHODE     4. COLLECTOR   4. COLLECTOR   4. BASE   4. ANODE 3   out in the datasheet refer to the callout. If style type is not callout. If style type is not callout. If style type is not callout. COLLECTOR     4. COLLECTOR   4. COLLECTOR   5. EMITTER   5. ANODE   out in the datasheet refer to the callout. If style type is not callout. If style type is not callout. COLLECTOR     5. COLLECTOR 2/BASE 1   5. COLLECTOR   5. EMITTER   5. ANODE   out in the datasheet refer to the callout. If style type is not callout. If style type is not callout. If style type is not call	DESCRIPTION:	SC-88A (SC-70-	5/SOT-353)			PAGE 1 OF 1
2. EMITTER   2. EMITTER   2. N/C   2. DRAIN 1/2   2. COMMON ANODE     3. BASE   3. BASE   3. ANODE 2   3. SOURCE 1   3. CATHODE 2     4. COLLECTOR   4. COLLECTOR   4. CATHODE 2   4. GATE 1   4. CATHODE 3     5. COLLECTOR   5. CATHODE   5. CATHODE 1   5. GATE 2   5. CATHODE 4     STYLE 6: STYLE 7: STYLE 8: STYLE 9: Note: Please refer to datasheet fr     PIN 1. EMITTER 2   PIN 1. BASE   PIN 1. CATHODE   PIN 1. ANODE   style callout. If style type is not callowed and the datasheet refer to the callowed and the datasheet referes to the callowed and the datasheet referesto the callowed and t	DOCUMENT NUMBER:	98ASB42984B				
2. EMITTER     2. EMITTER     2. N/C     2. DRAIN 1/2     2. COMMON ANODE       3. BASE     3. BASE     3. ANODE 2     3. SOURCE 1     3. CATHODE 2       4. COLLECTOR     4. COLLECTOR     4. CATHODE 2     4. GATE 1     4. CATHODE 3	PIN 1. EMITTER 2 2. BASE 2 3. EMITTER 1 4. COLLECTOR	PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR	PIN 1. CATHODE 2. COLLECTOR 3. N/C 4. BASE	PIN 1. ANODE 2. CATHODE 3. ANODE 4. ANODE	style callout. If style t out in the datasheet	type is not called refer to the device
STYLE 1: STYLE 2: STYLE 3: STYLE 4: STYLE 5:	PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR	PIN 1. ANODE 2. EMITTER 3. BASE 4. COLLECTOR	PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2	PIN 1. SOURCE 1 2. DRAIN 1/2 3. SOURCE 1 4. GATE 1	PIN 1. CATHODE 2. COMMON ANOU 3. CATHODE 2 4. CATHODE 3	DE

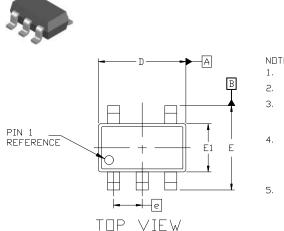
onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights of others.

XXX = Specific Device Code

M = Date Code = Pb-Free Package

<sup>(</sup>Note: Microdot may be in either location)



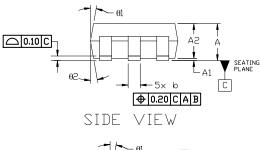


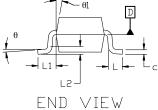


DATE 09 JUN 2021

NDTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 19894
- CONTROLLING DIMENSION: MILLIMETERS
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.25 PER SIDE. D AND E1 DIMENSIONS ARE DETERMINED AT DATUM D.
- DIMENSION 'b' DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08mm TOTAL IN EXCESS OF THE 'b' DIMENSION AT MAXIMUM MATERIAL CONDITION. MINIMUM SPACE BETWEEN PROTRUSION AND AN ADJACENT LEAD SHALL NOT BE LESS THAN 0.07mm.





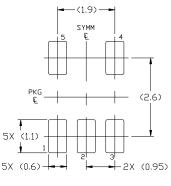
GENERIC **MARKING DIAGRAM\*** 



XXX = Specific Device Code = Date Code М

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

	MILLIMETERS					
DIM	MIN.	NDM.	MAX.			
А	0.90	—	1.45			
A1	0.00	_	0.15			
A2	0.90	1.15	1.30			
b	0.30	0.30 - 0.5				
С	0.08	—	0.22			
D	2	2.90 BSC				
E	2	.80 BSC				
E1	1	.60 BSC				
e	0.95 BSC					
L	0.30	0.60				
L1	0.60 REF					
L2	0.25 REF					
θ	0*	8*				
θ1	0°	10°	15°			
θ2	0*	10°	15°			



#### RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DOCUMENT NUMBER:	98AON34320E	Electronic versions are uncontrolled except when accessed directly from the Document Repository Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.					
DESCRIPTION:	SOT–23, 5 LEAD		PAGE 1 OF 1				

ON Semiconductor and 🔘 are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or indental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification. Buyer shall indemnify and hold onsemi and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs,

#### ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation onsemi Website: www.onsemi.com ONLINE SUPPORT: <u>www.onsemi.com/support</u> For additional information, please contact your local Sales Representative at www.onsemi.com/support/sales